

500mA, Low Quiescent, Low Dropout LDO Linear Regulators

ME6210 Series

General Description

ME6210 series are low quiescent, low-dropout linear voltage regulators.ME6210 series are based on the CMOS process and allow high voltage input .The allow operation voltage as high as 18V. ME6210 series have short circuit protection function.

Features

High output accuracy: ± 2%

Input voltage: 2V to 18 V

Output voltage: 1.5V ~ 5.0V

Ultra-low quiescent current (Typ. = 1.5 μ A)

Output Current: lout = 500mA
 (When Vin = 4V and Vout = 3V)
 Low dropout voltage: 11mV@ lout = 10mA (Typ. Vout = 3.0V)

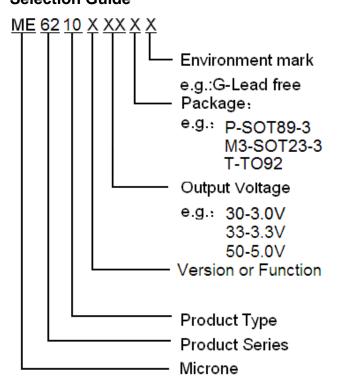
• Input good stability: Typ. 0.03% / V

Short-circuit Current:: Typ. 50mA

Ceramic capacitor can be used

Package: SOT89-3, SOT23-3, TO-92.

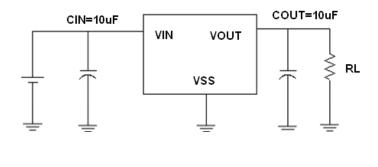
Selection Guide



Typical Application

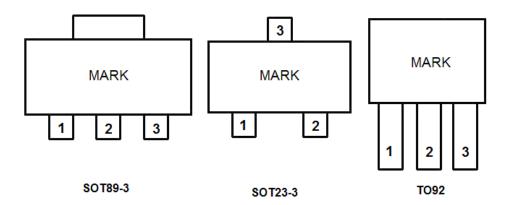
- Power source for home electric/electronic appliances
- Power source for battery-powered devices
- Power source for personal communication devices

Typical Application Circuit





Pin Configuration



Pin Assignment

ME6210AXX

Pin Nu	mber	Pin Name	Functions
SOT89-3 / TO92	SOT23-3	Fill Name	FullClions
1	1	V_{SS}	Ground
2	3	V _{IN}	Power Input
3	2	V _{OUT}	Output

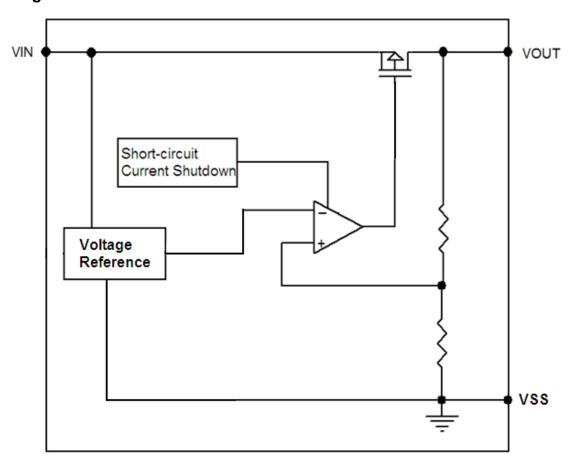
Absolute Maximum Ratings

Parameter		Symbol	Ratings	Units
Input Voltag	е	V _{IN}	18	V
Output Curre	nt	I _{OUT}	700	mA
Output Voltage	ge	V _{OUT}	Vss-0.3 \sim V $_{\rm IN}$ +0.3	V
	SOT89-3		500	mW
Power Dissipation	TO92	P_D	500	mW
	SOT23-3		300	mW
Operating Temperature Range		T _{OPR}	-25~+85	$^{\circ}$
Storage Temperature Range		T _{STG}	$-40 \sim +125$	$^{\circ}$
Lead Tempera	ture		260°C, 10sec	

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Block Diagram



Electrical Characteristics ME6210A30

(V_{IN}= V_{OUT}+1.0V, $C_{IN}=C_{OUT}=10uF$, Ta=25 O C, unless otherwise noted)

	V _{IN} = V _{OUT} +1.0V, G _{IN=COUT} =10di, 1a=23 G, diffess officerwise floted)					
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Output Voltage	V _{OUT} (E)	I _{OUT} =40mA,	X 0.98	V _{OUT} (T)	X 1.02	V
Output voltage	(Note 2)	V _{IN} =Vout+1V	X 0.96	(Note 1)	A 1.02	V
Input Voltage	V _{IN}				18	V
Maximum Output Current	I _{OUT} _max	V _{IN} =Vout+1V	500	500		mA
Load Regulation	ΔV_{OUT}	V _{IN} =Vout+1V,		12	30	mV
Load Negulation	AV001	1mA≤l _{OUT} ≤200mA		12	30	1110
	V _{DIF1}	I _{OUT} =10mA		11	14	mV
Dropout Voltage (Note 3)	V _{DIF2}	I _{OUT} =100mA		110	140	mV
(13.50)	V _{DIF3}	I _{OUT} =200mA		220	280	mV



Supply Current I _{SS}		V _{IN} =Vout+1V	1.5	2.5	μА
Line Regulations	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \times V_{OUT}}$	I _{OUT} =10mA Vout+1V ≤V _{IN} ≤18V	0.03	0.1	%/V
Temperature coefficient	$\frac{\Delta V_{\text{OUT}}}{\Delta \text{Ta } \times V_{\text{OUT}}}$	V _{IN} =Vout+1V ,I _{OUT} =10mA -40°C≤Ta≤125°C	±60	±100	Ppm/℃
Short-circuit Current	Ishort	V _{IN} =Vout+1V	50	70	mA

ME6210A33

(V_{IN} = V_{OUT} +1.0V, C_{IN} = C_{OUT} =10uF, Ta=25 O C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Output Voltage	V _{OUT} (E) (Note 2)	I _{OUT} =40mA, V _{IN} =Vout+1V	X 0.98	V _{OUT} (T) (Note 1)	X 1.02	V
Input Voltage	V _{IN}				18	V
Maximum Output Current	I _{OUT} _max	V _{IN} =Vout+1V	500	500		mA
Load Regulation	ΔV_OUT	V _{IN} =Vout+1V, 1mA≤I _{OUT} ≤200mA		12	30	mV
	V_{DIF1}	I _{OUT} =10mA		10	13	mV
Dropout Voltage (Note 3)	V_{DIF2}	I _{OUT} =100mA		100	130	mV
(232 2)	V_{DIF3}	I _{OUT} =200mA		200	260	mV
Supply Current	I _{SS}	V _{IN} =Vout+1V		1.6	2.5	μА
Line Regulations	$\frac{\Delta V_{\text{OUT}}}{\Delta V_{\text{IN}} \times V_{\text{OUT}}}$	I _{OUT} =10mA Vout+1V ≤V _{IN} ≤18V		0.03	0.1	%/V
Temperature coefficient	$\frac{\Delta V_{OUT}}{\Delta Ta \times V_{OUT}}$	V _{IN} =Vout+1V ,I _{OUT} =10mA -40 °C≤Ta≤125 °C		±60	±100	Ppm/℃
Short-circuit Current	Ishort	V _{IN} =Vout+1V		50	70	mA

ME6210A50

(V_{IN}= V_{OUT}+1.0V, $C_{IN}=C_{OUT}=10uF$, Ta=25 O C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Output Voltage	V _{OUT} (E) (Note 2)	I _{OUT} =40mA, V _{IN} =Vout+1V	X 0.98	V _{OUT} (T) (Note 1)	X 1.02	V
Input Voltage	V _{IN}				18	V
Maximum Output Current	I _{OUT} _max	V _{IN} =Vout+1V	500	500		mA
Load Regulation	ΔV_{OUT}	V _{IN} =Vout+1V, 1mA≤I _{OUT} ≤200mA		10	30	mV



	V _{DIF1}	I _{OUT} =10mA	8	11	mV
Dropout Voltage (Note 3)	V_{DIF2}	I _{OUT} =100mA	80	110	mV
(V_{DIF3}	I _{OUT} =200mA	160	220	mV
Supply Current	I _{SS}	V _{IN} =Vout+1V	1.7	2.5	μА
Line Regulations	$\frac{\Delta V_{\text{OUT}}}{\Delta V_{\text{IN}} \times V_{\text{OUT}}}$	I _{OUT} =10mA Vout+1V ≤V _{IN} ≤18V	0.03	0.1	%/V
Temperature coefficient	$\frac{\Delta V_{OUT}}{\Delta Ta \times V_{OUT}}$	V _{IN} =Vout+1V ,I _{OUT} =10mA -40°C≤Ta≤125°C	±60	±100	Ppm/℃
Short-circuit Current	Ishort	V _{IN} =Vout+1V	50	70	mA

Note:

1. V_{OUT} (T): Specified Output Voltage

2.V_{OUT} (E) : Effective Output Voltage (ie. The output voltage when "V_{OUT} (T)+1.0V" is provided at the Vin pin while maintaining a certain lout value.)

3.V_{DIF}: V_{IN1} –V_{OUT} (E)'

 V_{IN1} : The input voltage when $V_{\text{OUT}}(E)$ ' appears as input voltage is gradually decreased.

 V_{OUT} (E)'=A voltage equal to 98% of the output voltage whenever an amply stabilized lout and $\{V_{OUT}$ (T) +1.0V} is input.

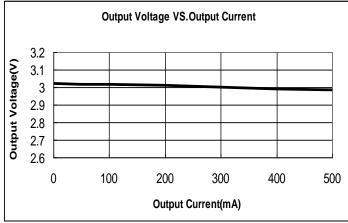
Precautions

- During the test, if AC/DC power supply and the ceramic chip capacitors collocation is used, there may be serious voltage spike phenomenon instantaneously. When the power supply access to 15V, the voltage is rushed to about 30V instantaneously. Because of exceeding the limit voltage of chip, the chip is damaged. If you string a small resistance of 1 ohm in the input end during the test, the peak phenomenon can be avoided.
- In the test, there is serious burr phenomenon only when the AC/DC power is used with ceramic chip capacitors. But electrolytic capacitors and tantalum capacitance won't appear above phenomenon. Please be sure to pay attention to this point when you use AC/DC power.
- In normal use, when any type of capacitor is used with battery or the supply of fire power, the above phenomenon doesn't occur.

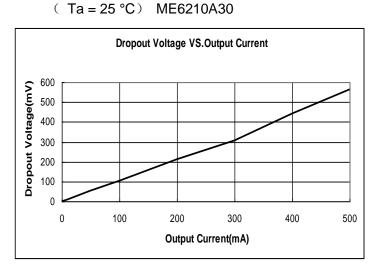


Type Characteristics

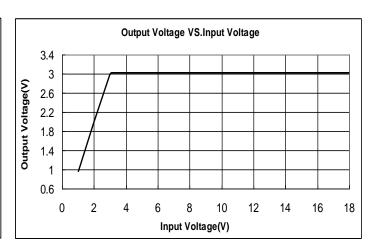
Output Voltage VS. Output Current ($Ta = 25 \, ^{\circ}\text{C}$, VIN=4V) ME6210A30



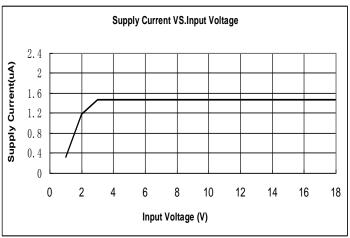
(3) Dropout Voltage VS. Output Current



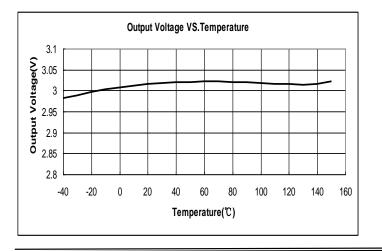
(2) Output Voltage VS. Input Voltage $(Ta = 25 \, ^{\circ}C, Iout=10mA) ME6210A30$



(4) Supply Current VS. Input Voltage (Ta = 25 °C) ME6210A30



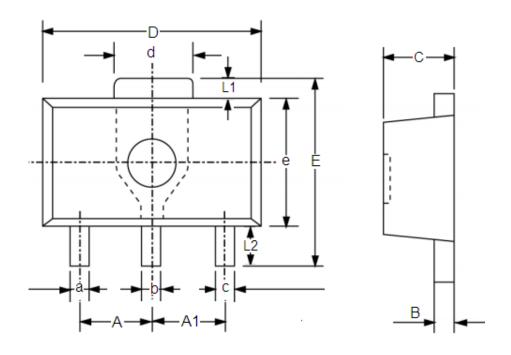
(5) Output Voltage VS. Temperature (VIN=4V ,lout=10mA) ME6210A30





Packaging Information

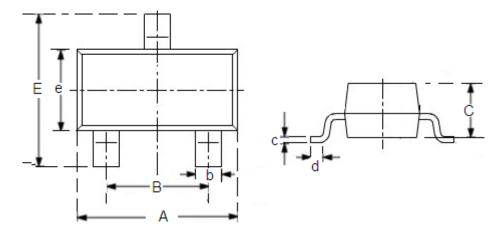
• SOT89-3



DIM	Millim	neters	Ir	nches
DIM	Min	Max	Min	Max
А	1.4	1.6	0.0551	0.0630
A1	1.4	1.6	0.0551	0.0630
а	0.36	0.48	0.0142	0.0189
b	0.41	0.53	0.0161	0.0209
С	0.36	0.48	0.0142	0.0189
d	1.4	1.75	0.0551	0.0689
В	0.38	0.43	0.015	0.0169
С	1.4	1.6	0.0551	0.0630
D	4.4	4.6	0.1732	0.181
Е	-	4.25	-	0.1673
е	2.4	2.6	0.0945	0.1023
L1	0.4	-	0.0157	-
L2	0.8	-	0.0315	-



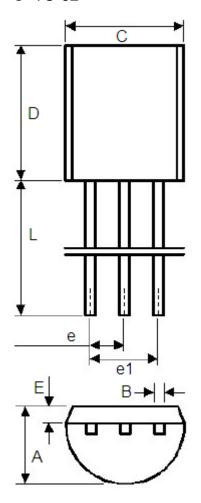
• SOT23-3



DIM	Millimeters		Inches	
DIM	Min	Max	Min	Max
А	2.7	3.1	0.1063	0.122
В	1.7	2.1	0.0669	0.0827
b	0.35	0.5	0.0138	0.0197
С	1.0	1.2	0.0394	0.0472
С	0.1	0.25	0.0039	0.0098
d	0.2	-	0.0079	-
E	2.6	3.0	0.1023	0.1181
е	1.5	1.8	0.059	0.0708



• TO-92



	Min	Max	Min	Max
Α	3.4	3.8	0.13386	0.1496
В	0.3	0.5	0.0118	0.0197
С	4.4	4.8	0.1732	0.189
D	4.4	4.8	0.1732	0.189
E	0.9	1.5	0.0354	0.059
е	1.17	1.37	0.046	0.0539
e1	2.39	2.69	0.094	0.1059
L	12	16	0.4724	0.6299



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